

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P18AQ uses advanced trench technology to provide excellent $R_{DS(ON)}$, This device is suitable for use as a load switch or power management.

Application

- Power management
- Load switch

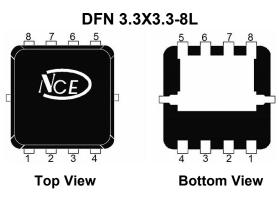
General Features

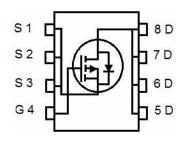
• V_{DS} = -60V,I_D = -18A

 $R_{DS(ON)}$ <37m Ω @ V_{GS}=-10V

- R_{DS(ON)} <55mΩ @ V_{GS}=-4.5V
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

100% UIS TESTED! 100% ΔVds TESTED!





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P18AQ	NCE60P18AQ	DFN3.3X3.3-8L	-	-	-

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	-18	А
Drain Current-Continuous(T _c =100 ℃)	I _D (100℃)	-12.7	A
Pulsed Drain Current	I _{DM}	-72	A
Maximum Power Dissipation	PD	40	W
Derating factor		0.27	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	156	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic



Electrical Characteristics (Tc=25 $^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	· · ·		•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.0	-1.75	-2.5	V
Drain Sauras On State Desistance	D	V _{GS} =-10V, I _D =-10A	-	32	37	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-10A	-	44	55	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-10A	-	20	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	Clss	V _{DS} =-30V,V _{GS} =0V,	-	1920	-	PF
Output Capacitance	Coss		-	124	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	97	-	PF
Switching Characteristics (Note 4)	· · ·		•			
Turn-on Delay Time	t _{d(on)}		-	12	-	nS
Turn-on Rise Time	tr	V _{DD} =-30V,I _D =-10A	-	14	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V, R_{GEN} =3 Ω	-	38	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	<u>)/ 00)/1 404</u>	-	36.5	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-30V,I _D =-10A,	-	6.9	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	8.2	-	nC
Drain-Source Diode Characteristics	· · · · · ·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-10A	-	-	1.2	V
Diode Forward Current (Note 2)	ls		-	-	-10	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = -10A	-	-	40	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	-	70	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

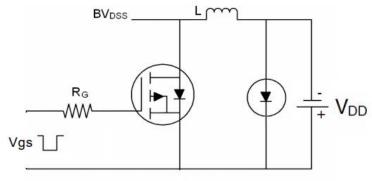
4. Guaranteed by design, not subject to production

5. EAS condition: Tj=25 $^\circ\!\!\!\mathrm{C}$,V_DD=-30V,V_G=-10V,L=0.5mH,Rg=25 Ω

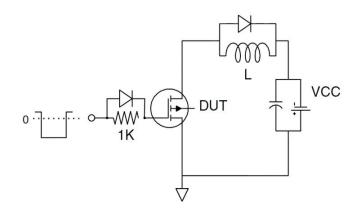


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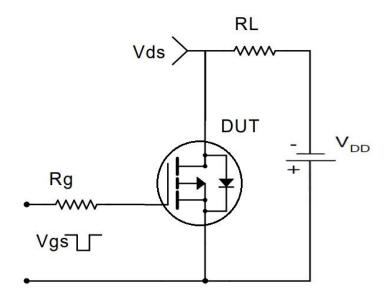
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

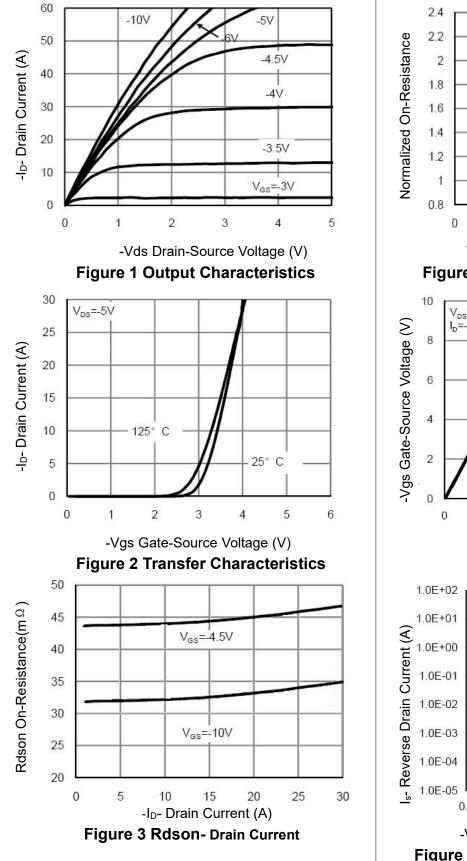


3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)



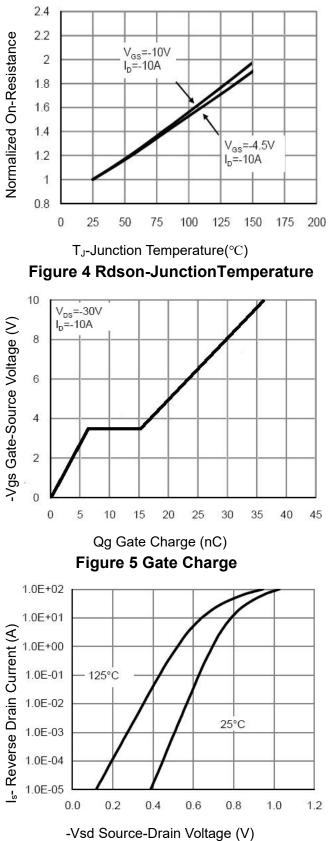


Figure 6 Source- Drain Diode Forward



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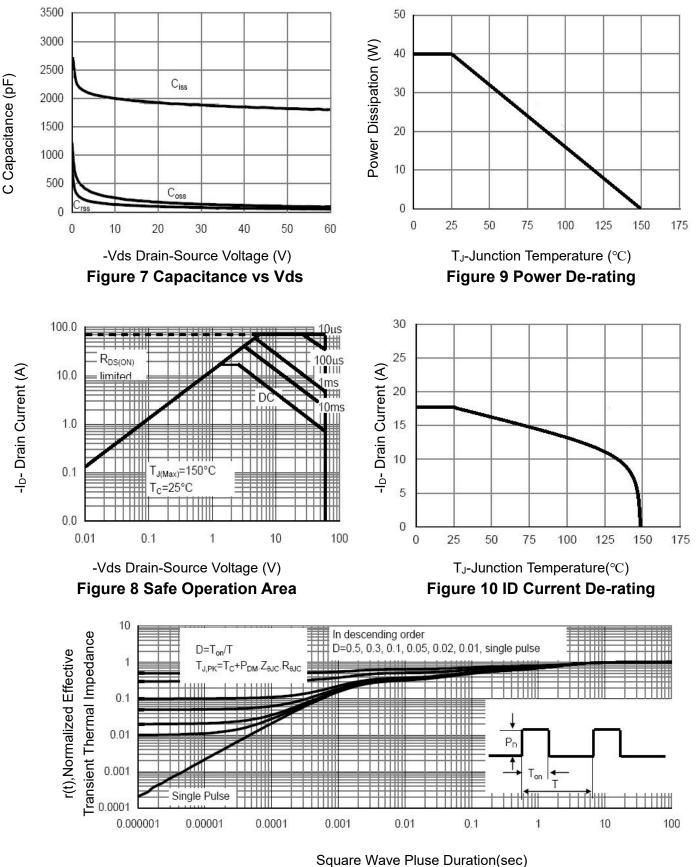
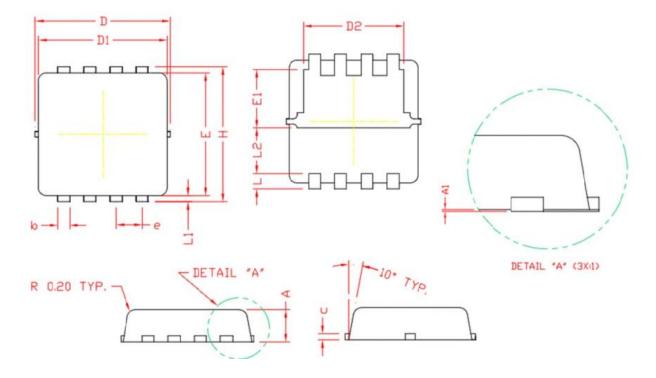


Figure 11 Normalized Maximum Transient Thermal Impedance







COMMON DIMENSIONS

(UNITS	OF MEAS	URE=MILI	IMETER)	
SYMBOL	MIN	NOM	MAX	
A	0.70	0.80	0.90	
A1	0.00	0.03	0.05	
b	0.24	0.30	0.35	
с	0.10	0.15	0.20	
D	3.25	3.32	3.40	
D1	3.05	3.15	3.25	
D2	2.40	2.50	2.60	
E	3.00	3.10	3.20	
E1	1.35	1.45	1.55	
е	0.65 BSC.			
Н	3.20	3.30	3.40	
L	0.30	0.40	0.50	
L1	0.10	0.15	0.20	
L2	1.13 REF.			

Wuxi NCE Power Co., Ltd



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